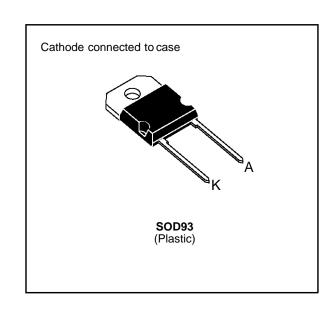


BYT 60P-200→400

FAST RECOVERY RECTIFIER DIODES

- VERY LOW REVERSE RECOVERY TIME
- VERY LOW SWITCHING LOSSES
- LOW NOISE TURN-OFF SWITCHING



SUITABLE APPLICATIONS:

- FREE WHEELING DIODE IN CONVERTERS AND MOTOR CONTROL CIRCUITS
- RECTIFIER IN S.M.P.S.

ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value	Unit	
I _{FRM}	Repetitive Peak Forward Current	t _p ≤ 10μs	800	Α
I _{F (RMS)}	RMS Forward Current		100	Α
I _{F (AV)}	Average Forward Current	$T_c = 70^{\circ}C$ $\delta = 0.5$	60	А
I _{FSM}	Surge non Repetitive Forward Current	t _p = 10ms Sinusoidal	550	А
Р	Power Dissipation	T _c = 70°C	100	W
T _{stg} T _j	Storage and Junction Temperature Range		- 40 to + 150 - 40 to + 150	°C

Symbol	Parameter		BYT 60P-			
Cymbol			300	400	Unit	
V _{RRM}	Repetitive Peak Reverse Voltage	200	300	400	V	
V _{RSM}	Non Repetitive Peak Reverse Voltage	220	330	440	V	

THERMAL RESISTANCE

Symbol	Parameter	Value	Unit
R _{th (j-c)}	Junction-case	0.8	°C/W

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ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

Synbol	Test Conditions			Тур.	Max.	Unit
I _R	T _j = 25°C	$V_R = V_{RRM}$			60	μΑ
	T _j = 100°C				10	mA
V _F	T _j = 25°C	I _F = 60A			1.5	V
	T _j = 100°C				1.4	

RECOVERY CHARACTERISTICS

Symbol	Test Conditions				Min.	Тур.	Max.	Unit
t _{rr}	T _j = 25°C	I _F = 1A	$di_F/dt = -15A/\mu s$	$V_R = 30V$			100	ns
		I _F = 0.5A	I _R = 1A	$I_{rr} = 0.25A$			50	

TURN-OFF SWITCHING CHARACTERISTICS (Without Series Inductance)

Symbol	Test Conditions			Тур.	Max.	Unit
t _{IRM}	di _F /dt = - 240A/μs	V _{CC} = 200 V I _F = 60A			75	ns
	di _F /dt = - 480A/μs	$L_p \le 0.05 \mu H$ $T_j = 100$ °C See Figure 11		50		
I _{RM}	di _F /dt = - 240A/μs				18	Α
	di _F /dt = - 480A/μs			24		

TURN-OFF OVERVOLTAGE COEFFICIENT - (With Series Inductance)

Symbol	Test Condition s			Min.	Тур.	Max.	Unit
$C = \frac{V_{RP}}{V_{CC}}$	T _j = 100°C di _F /dt = - 60A/μs	$V_{CC} = 120V$ $L_p = 1.3 \mu H$	$I_F = I_{F (AV)}$ See note See figure 12		3.3		

Note: Applicable to BYT 60P-400 only

To evaluate the conduction losses use the following equations:

$$V_F = 1.1 + 0.0045 I_F$$
 $P = 1.1 \times I_{F(AV)} + 0.0045 I_F^2(RMS)$

Figure 1. Low frequency power losses versus average current.

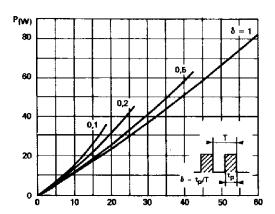


Figure 2. Peak current versus form factor.

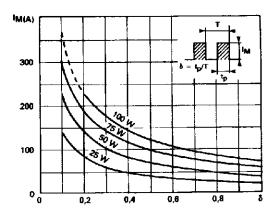


Figure 3. Non repetitive peak surge current versus overload duration

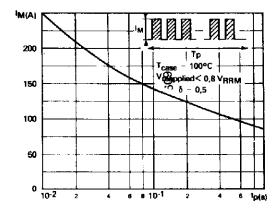


Figure 4. Thermal impedance versus pulse width.

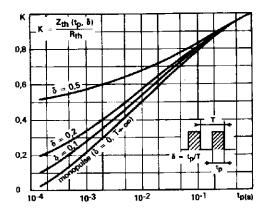


Figure 5. Voltage drop versus forward current.

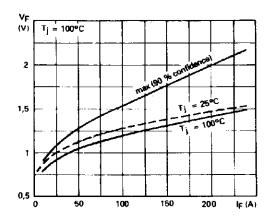


Figure 6. Recovery charge versus di_F/dt.

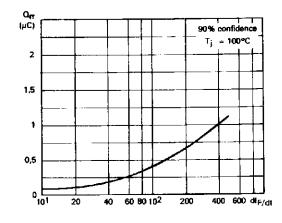


Figure 7. Recovery time versus di_F/dt.

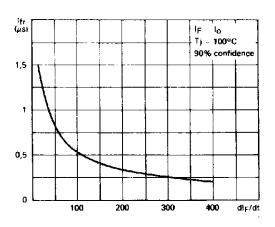


Figure 8. Peak reverse current versus dif/dt.

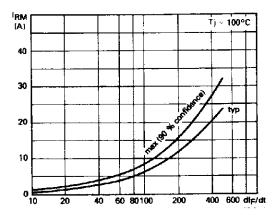


Figure 9. Peak forward voltage versus di_F/dt.

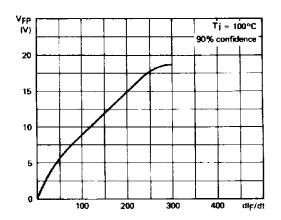


Figure 10. Dynamic parameters versus junction temperature.

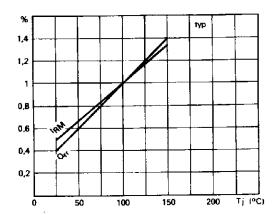


Figure 11. Turn-off switching characteristics (without series inductance).

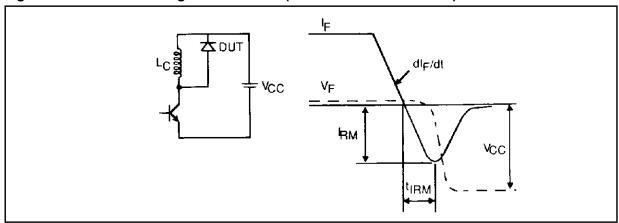
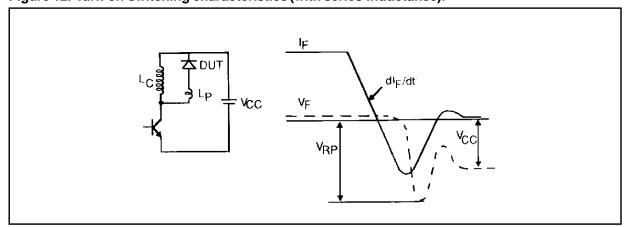
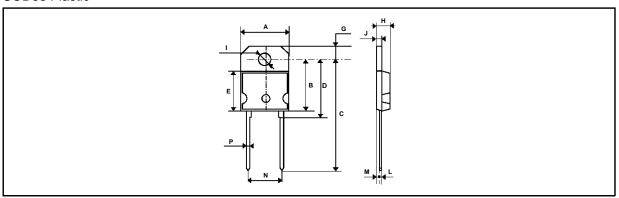


Figure 12. Turn-off switching characteristics (with series inductance).



PACKAGE MECHANICAL DATA

SOD93 Plastic



	DIMENSIONS					
REF.	Millimeters		Inc	hes		
	Min.	Max.	Min.	Max.		
Α	14.7	15.2	0.578	0.596		
В		16.2		0.637		
С	31 typ		1.220 typ			
D	18 typ		0.708 typ			
E		12.2		0.480		
G	3.95	4.15	0.155	0.163		
Н	4.7	4.9	0.185	0.193		
I	4	4.1	0.157	0.161		
J	1.17	1.37	0.046	0.054		
L	0.5	0.78	0.019	0.030		
M	2.5 typ	5 typ 0.098 typ				
N	10.8	11.1	0.425	0.437		
Р	1.1	1.3	0.043	0.051		

Cooling method: by conduction (method C)

Marking: type number Recommended torque value: 80cm. N Maximum torque value: 100cm. N

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